

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/806,224	06/11/2001	Hartmut Grutzediek	1477.011	4906
23405	23405 7590 01/11/2005		EXAMINER	
HESLIN RO	OTHENBERG FARLE	FOURSON III	FOURSON III, GEORGE R	
ALBANY, NY 12203			ART UNIT	PAPER NUMBER
•			2823	

DATE MAILED: 01/11/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)			
Office Action Summary						
		09/806,224	GRUTZEDIEK ET AL.			
		Examiner	Art Unit			
		George Fourson	be correspondence address			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
THE - Exte after - If the - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. nsions of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period we are to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing red patent term adjustment. See 37 CFR 1.704(b).	6(a). In no event, however, may a reply within the statutory minimum of thirty (30 ill apply and will expire SIX (6) MONTHS cause the application to become ABAND	be timely filed) days will be considered timely. from the mailing date of this communication. ONED (35 U.S.C. § 133).			
Status	·					
1)	Responsive to communication(s) filed on 20 Oc	ctober 2004.				
· · · · · ·	This action is FINAL . 2b) \boxtimes This action is non-final.					
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
5)□ 6)⊠ 7)□	Claim(s) 1-27 and 29-31 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. Claim(s) is/are allowed. Claim(s) 1-27 and 29-31 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/or election requirement.					
Applicat	ion Papers					
10)	The specification is objected to by the Examine The drawing(s) filed on is/are: a) access Applicant may not request that any objection to the Replacement drawing sheet(s) including the correction The oath or declaration is objected to by the Examine	epted or b) objected to by the drawing(s) be held in abeyance. on is required if the drawing(s) is	See 37 CFR 1.85(a). s objected to. See 37 CFR 1.121(d).			
Priority (under 35 U.S.C. § 119		·			
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 						
2) Notice 3) Information	et(s) te of References Cited (PTO-892) te of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) tr No(s)/Mail Date	Paper No(s)/M	mary (PTO-413) ail Date nal Patent Application (PTO-152)			

Application/Control Number: 09/806,224

Art Unit: 2823

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 10/20/04 has been entered.

The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

Claims 1-27 and 29-31 are rejected under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement. The claim(s) contains subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention. There is no description in the disclosure as originally filed of "the p-doped or n-doped inner area having a same doping concentration as the starting semiconductor substrate".

Applicant points to Figures 1 and 2 submitted with the amendment filed 10/20/04. Although Figure 2 shows zero concentration of dopant at depths up to about 1 micron when using an energy of 6 MeV, Figure 1 shows non-zero concentrations for a lower dose implant at that energy. If Figure 1 is accurate there is no way to reconcile the difference shown for the resulting profile in Figure 2. The higher dose used in the process of Figure 2 would be expected to result in a higher concentration of dopants at all depths compared to the process of Figure 1. Also see Cheung et al, newly cited, Figures 2 and 3, which show results for P implantation at energies below and above 6 MeV.

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. See Goo at Figures 2A-2C which results from an energy of several electron volts (col.4) and the disclosure at column 5 that the implant does not adversely affect device properties. See Odanaka at figures 2a-2d and claim 5. See Seliskar et al at figure 4 and col.3 wherein options related to mask material, ion, dose and energy are disclosed.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to George Fourson whose telephone number is (571) 272-1860. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri, can be reached on (571) 272-1855. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

George Fourson
Primary Examiner
Art Unit 2823

GFourson January 9, 2005